

CSM312N4S23

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

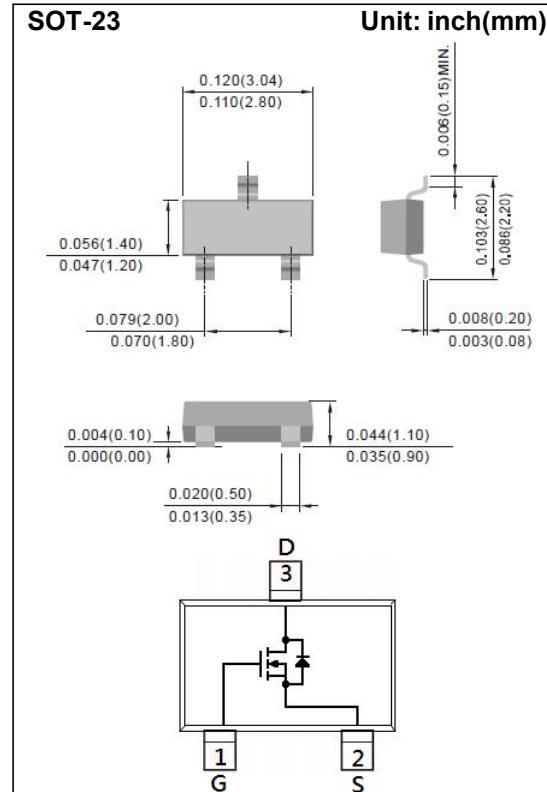
4 A

Features

- R_{DS(ON)}, V_{GS}@10V, I_D@4.0A<45mΩ
- R_{DS(ON)}, V_{GS}@4.5V, I_D@3.6A<53mΩ
- R_{DS(ON)}, V_{GS}@2.5V, I_D@2.5A<66mΩ
- R_{DS(ON)}, V_{GS}@1.8V, I_D@1.5A<92mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	± 12	V
Continuous Drain Current	I _D	4.0	A
Pulsed Drain Current	I _{DM}	16.0	A
Power Dissipation	P _D	1.25	W
Derate above 25°C		10	mW/ °C
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)	R _{θJA}	100	°C/W

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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	30	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	0.4	0.72	1.2	V
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=4.0\text{A}$	-	37	45	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=3.6\text{A}$	-	40	53	
		$V_{\text{GS}}=2.5\text{V}, I_{\text{D}}=2.5\text{A}$	-	48	66	
		$V_{\text{GS}}=1.8\text{V}, I_{\text{D}}=1.5\text{A}$	-	62	92	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}$	-	0.01	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	-	± 10	± 100	nA
Dynamic						
Total Gate Charge	Q_g	$V_{\text{DS}}=15\text{V}, I_{\text{D}}=4.0\text{A}, V_{\text{GS}}=10\text{V}$ (Note 1,2)	-	11.3	-	nC
Gate-Source Charge	Q_{gs}		-	1	-	
Gate-Drain Charge	Q_{gd}		-	1.2	-	
Input Capacitance	C_{iss}	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHz}$	-	447	-	pF
Output Capacitance	C_{oss}		-	34	-	
Reverse Transfer Capacitance	C_{rss}		-	22	-	
Switching						
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=15\text{V}, I_{\text{D}}=4.0\text{A}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=3\Omega$ (Note 1,2)	-	1.7	-	ns
Turn-On Rise Time	t_{r}		-	38	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	82	-	
Turn-Off Fall Time	t_{f}		-	64	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	1.5	A
Diode Forward Voltage	V_{SD}	$I_s=1.0\text{A}, V_{\text{GS}}=0\text{V}$		0.77	1.2	V

NOTES :

1. Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{JJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited

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TYPICAL CHARACTERISTIC CURVES

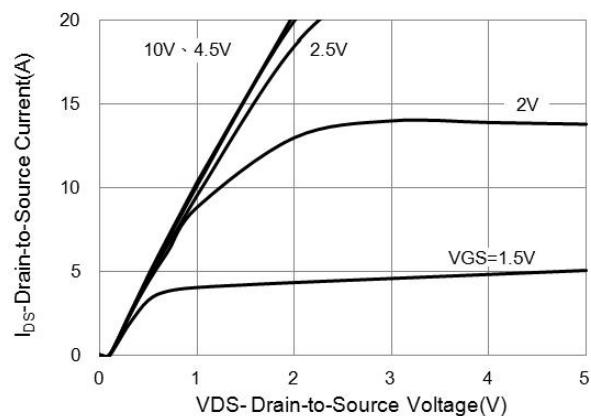


Fig.1 On-Region Characteristics

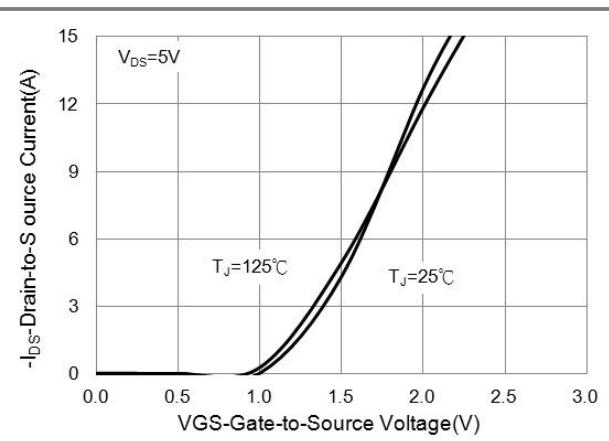


Fig.2 Transfer Characteristics

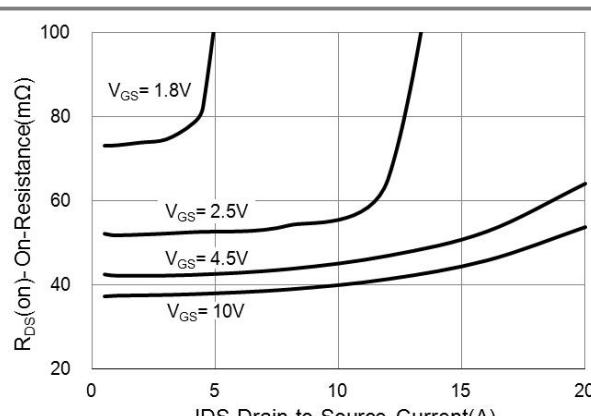


Fig.3 On-Resistance vs. Drain Current

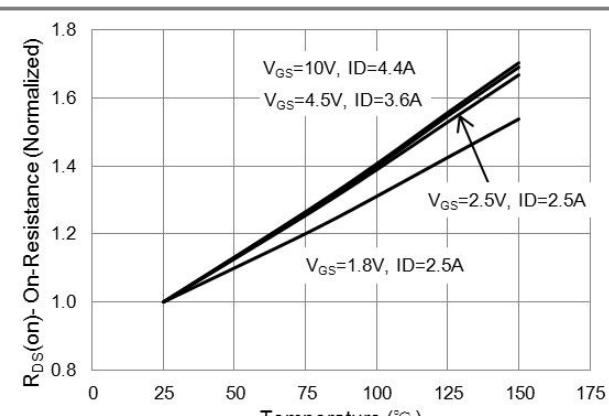


Fig.4 On-Resistance vs. Junction temperature

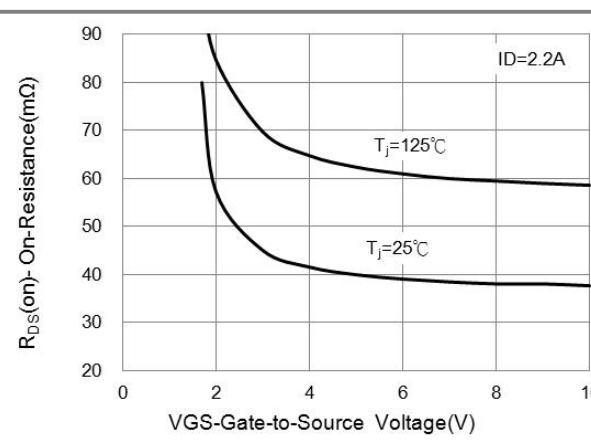


Fig.5 On-Resistance Variation with VGS.

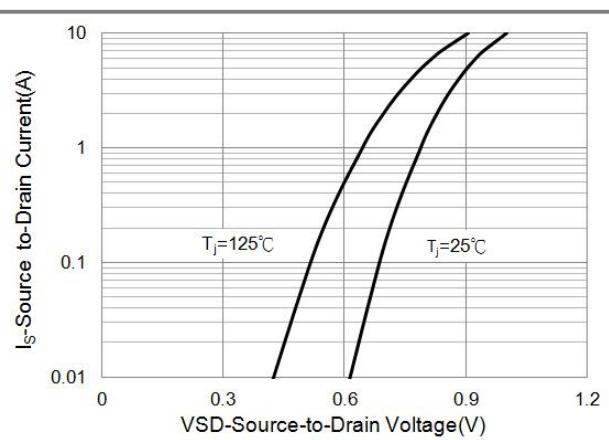


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

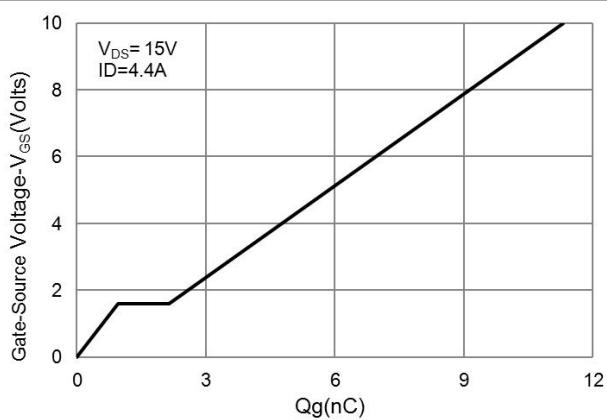


Fig.7 Gate-Charge Characteristics

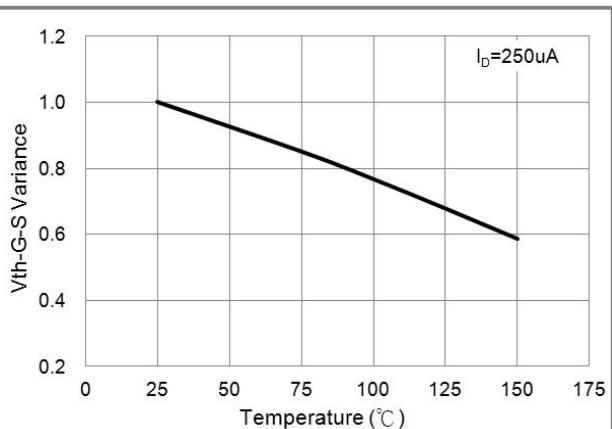


Fig.8 Threshold Voltage Variation with Temperature.

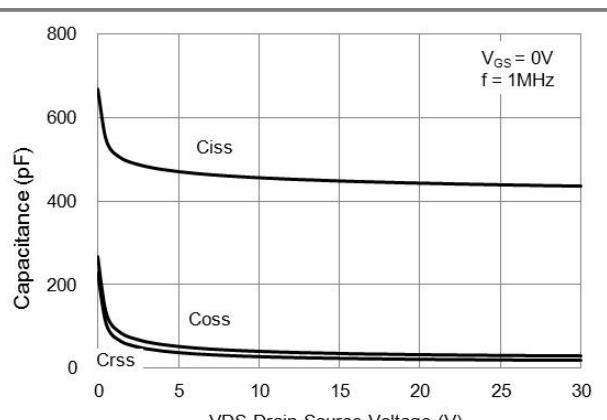


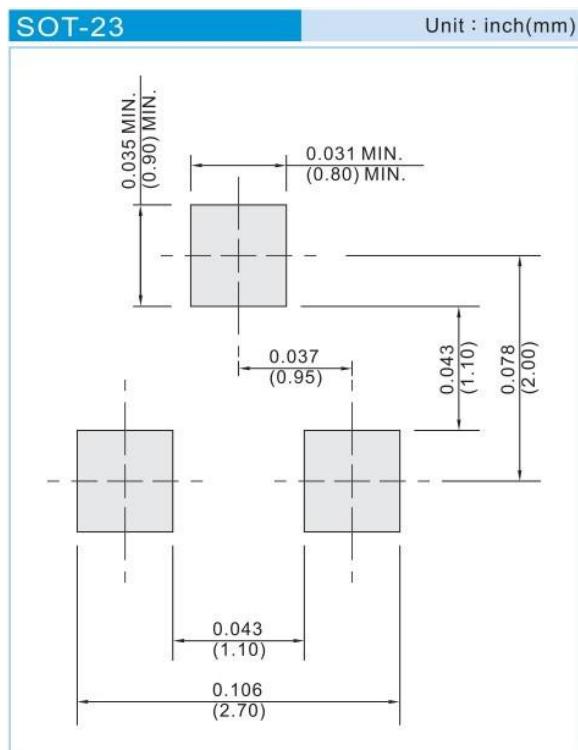
Fig.9 Capacitance vs. Drain-Source Voltage.

CSM312N4S23

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
CSM312N4S23	SOT-23	3K pcs / 7" reel		Halogen free

MOUNTING PAD LAYOUT



CSM312N4S23

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